EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3406	CMOS and ESD	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/08 15:54
L2	38	1 and ((ESD protect$3) near20 terminal near20 (capacitance capacitor) near20 resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/08 15:57
L3	6	("5301081" | "5400202" | "5838146" | "5959488" | "5995354" | "6097235").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/06/08 15:41
L4	0	("6611407").URPN.	USPAT	OR	ON	2006/06/08 15:42
L5	36541	(CMOS or (complementary adj metal adj oxide adj semiconductor)) and (ESD or electrostatic or protection or discharge)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/08 15:57
L6	3862	((ESD or electrostatic or discharge or protect$3) near20 terminal near20 (capacitance capacitor) near20 resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/08 15:57
L7	224	5 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/08 15:58
L8	186	7 not 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/08 15:58